

N-Channel 20 V (D-S) MOSFET

DESCRIPTION

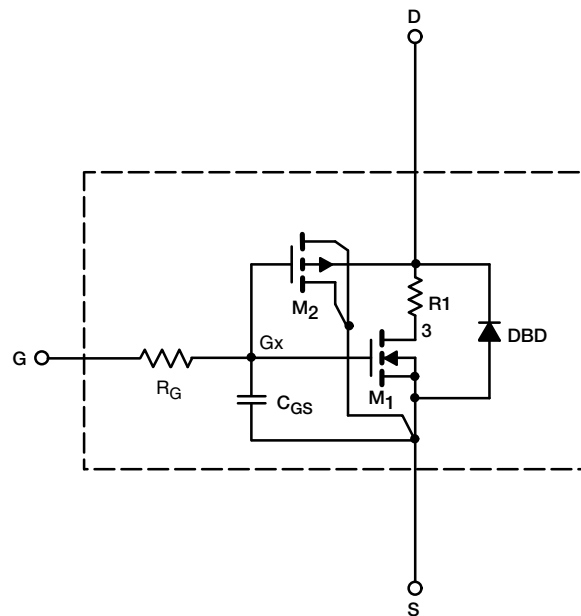
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 4.5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

- This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



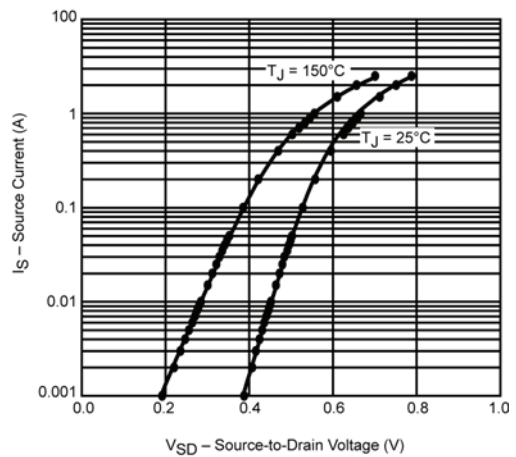
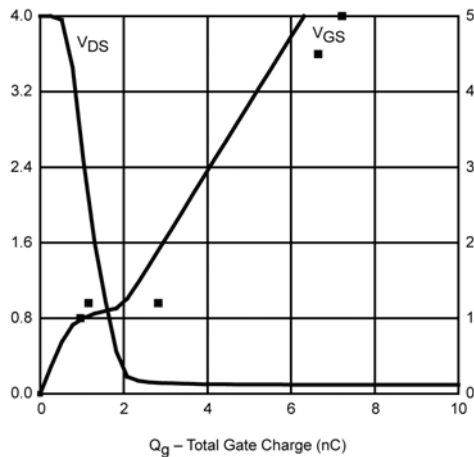
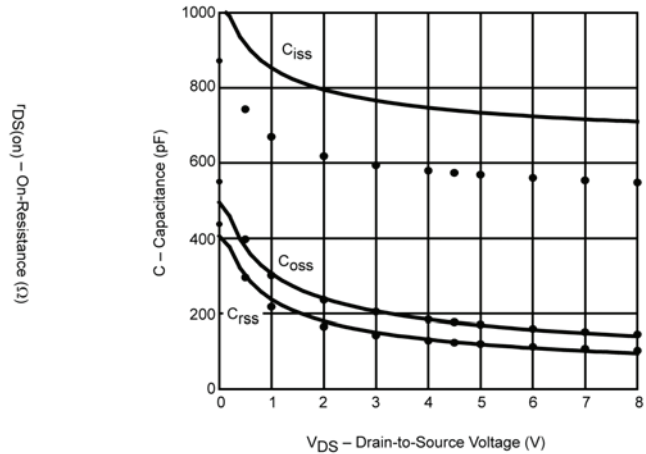
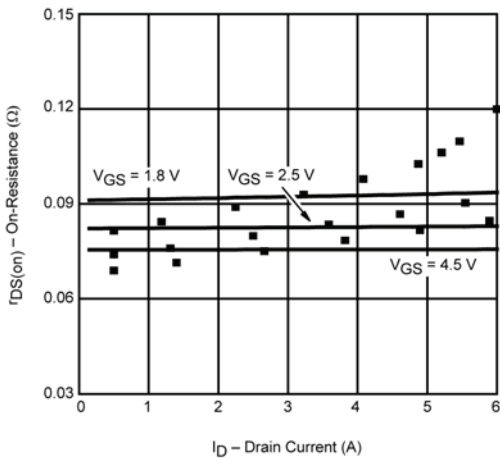
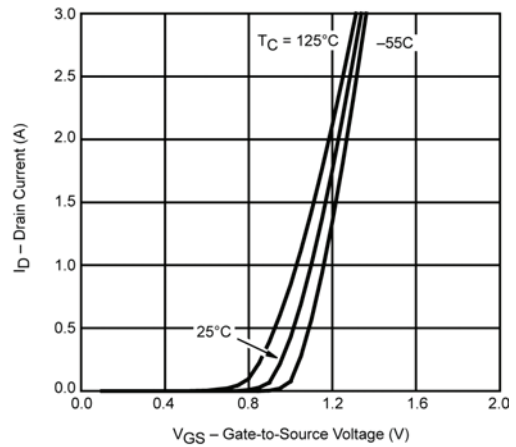
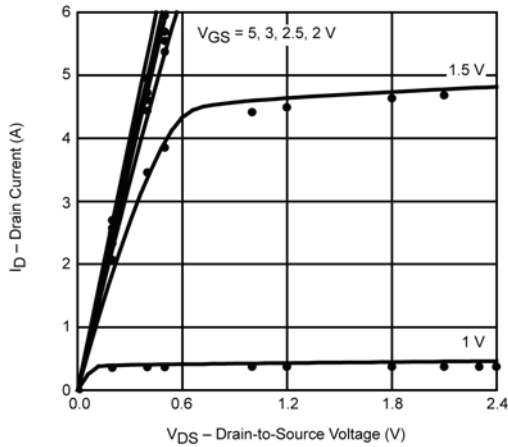
| SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted) | | | | | |
|---|--------------|---|----------------|---------------|----------|
| PARAMETER | SYMBOL | TEST CONDITIONS | SIMULATED DATA | MEASURED DATA | UNIT |
| Static | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 250\text{ }\mu\text{A}$ | 0.58 | - | V |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{DS} \leq 5\text{ V}$, $V_{GS} = 4.5\text{ V}$ | 56 | - | A |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = 4.5\text{ V}$, $I_D = 1.34\text{ A}$ | 0.076 | 0.071 | Ω |
| | | $V_{GS} = 2.5\text{ V}$, $I_D = 1.29\text{ A}$ | 0.083 | 0.078 | |
| | | $V_{GS} = 1.8\text{ V}$, $I_D = 1.23\text{ A}$ | 0.093 | 0.085 | |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = 4\text{ V}$, $I_D = 1.34\text{ A}$ | 8 | 4.12 | S |
| Diode Forward Voltage ^a | V_{SD} | $I_S = 1\text{ A}$ | 0.86 | 0.80 | V |
| Dynamic ^b | | | | | |
| Input Capacitance | C_{iss} | $V_{DS} = 4\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$ | 748 | 585 | pF |
| Output Capacitance | C_{oss} | | 185 | 190 | |
| Reverse Transfer Capacitance | C_{rss} | | 132 | 130 | |
| Total Gate Charge | Q_g | $V_{DS} = 4\text{ V}$, $V_{GS} = 5\text{ V}$, $I_D = 1.34\text{ A}$ | 6.4 | 7.7 | nC |
| | | $V_{DS} = 4\text{ V}$, $V_{GS} = 4.5\text{ V}$, $I_D = 1.34\text{ A}$ | 5.7 | 7.1 | |
| Q_{gs} | 1.14 | | 1.14 | | |
| Gate-Drain Charge | Q_{gd} | | 1.69 | 1.69 | |

Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.



COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Note

- Dots and squares represent measured data.

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